Green Laser Diode in TO56 Package Version 0.3

PLT5 520



Features

- Optical output power (continuous wave): 30 / 50 mW ($T_{case} = 25 \, ^{\circ}$ C)
- Typical emission wavelength: 520 nm
- Efficient radiation source for cw and pulsed operation
- Single transverse mode semiconductor laser
- · High modulation bandwidth
- TO56 package with photo diode

Applications

- Laser projection
- · Laser shows
- · Biomedical Applications
- Metrology

Safety Advice

Depending on the mode of operation, these devices emit highly concentrated visible light which can be hazardous to the human eye. Products which incorporate these devices have to follow the safety precautions found in IEC 60825-1 "Safety of laser products".



ATTENTION - Observe Precautions For Handling - Electrostatic Sensitive Device



Ordering Information

Туре:	Optical Output Power	Ordering Code
	$P_{\text{opt}} (T_{\text{case}} = 25^{\circ}\text{C})$	
PLT5 520_B1-3	50 mW	Q65111A5771
PLT5 520_B1-6	30 mW	Q65111A6145

Maximum Ratings

Operation outside these conditions may damage the device. Operation at maximum ratings may influence lifetime.

Parameter	Symbol	Values		Unit
		min.	max.	
Operating Current	I _F		200	mA
Operating Temperature	T _{case}	- 20	+ 60	°C
Storage Temperature	$T_{\rm stg}$	- 40	+ 85	°C
Reverse Voltage	V_{R}		2	٧
Soldering Temperature max. 10 sec.	$T_{\rm solder}$		260	°C
Junction temperature	$T_{\rm j}$		150	°C

Laser Characteristics ($T_{case} = 25 \, ^{\circ}\text{C}$)

Parameter	Symbol	Values			Unit	
		min.	typ.	max.		
Emission Wavelength ^{1) 2) 3)}	B1; B4	λ_{peak}	510	_	515	nm
-	B2; B5	p	515	-	520	nm
	B3; B6		520	-	530	nm
Spectral Width (FWHM) 1)		Δλ	-	2	-	nm
Threshold Current	B1-B3	I _{th}	-	45	75	mA
	B4-B6		-	50	75	mA
Operating Current 1) 2)	B1-B3	I _E	_	125	160	mA
	B4-B6		-	100	140	mA
Operating Voltage 1) 2)	B1-B3	$V_{\scriptscriptstyle \sf F}$	_	6.9	8.0	٧
	B4-B6		-	6.5	8.0	٧
Beam Divergence (FWHM) 1)		θ ₁₁ x	5 x	7 x	9 x	deg
,		$\theta_{\parallel} \times \theta_{\perp}$	19	22	25	
Polarization 1)		$P_{\rm gr}$	_	100:1	_	
Modulation Frequency		f	-	>100	-	MHz
Thermal resistance (junction to case)		R_{th}	-	34	-	K/W
Monitor current 1) 3)		I _m	_	90	_	μΑ

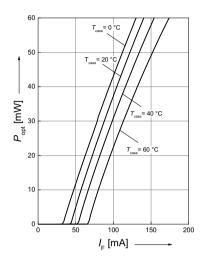
¹⁾ Standard operating conditions refer to a continuous wave output power of P_{opt} = 50 mW (B1-B3) and P_{opt} = 30 mW (B4-B6).

P_{opt}, λ_{peak}, and V_F is measured with an internal reproducibility of ±7%, ±0.3 nm, and ±0.05 V, respectively (acc. to GUM with a coverage factor of k = 3).

Monitor current refers to a reverse voltage of V = 5 V.

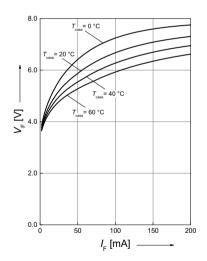
Optical Output Power (B1-B3)

 $P_{\text{opt}} = f(I_{\text{F}})$



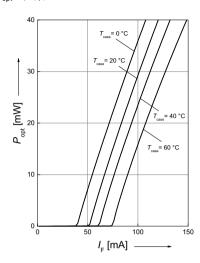
Operating Voltage (B1-B3)

 $V_{\mathsf{F}} = f \left(I_{\mathsf{F}} \right)$



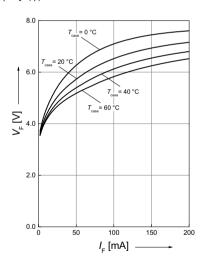
Optical Output Power (B4-B6)

 $P_{\text{opt}} = f(I_{\text{F}})$



Operating Voltage (B4-B6)

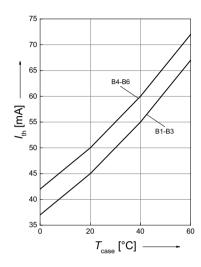
 $V_{\mathsf{F}} = f(I_{\mathsf{F}})$



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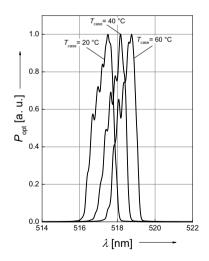
Threshold Current

$$I_{\rm th} = f \left(T_{\rm case} \right)$$



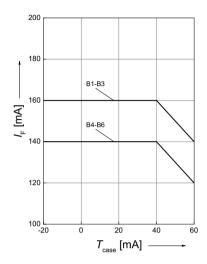
Spectra (B2; B5)

$$P_{\text{opt}} = f(\lambda)$$



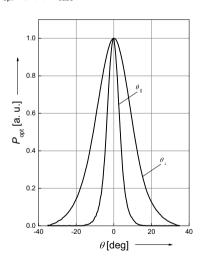
Maximum Recommended Operating Current

$$I_{\mathsf{F}} = f \left(T_{\mathsf{case}} \right)$$



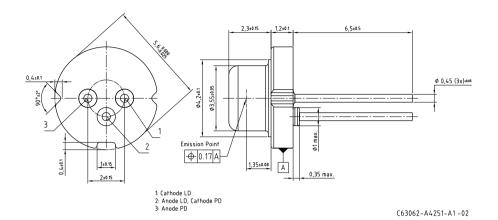
Beam Divergence

$$P_{\text{opt}} = f(\theta), T_{\text{case}} = 25 \,^{\circ}\text{C}$$



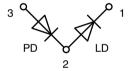
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Package Outline



Dimensions in mm

Pin Connection



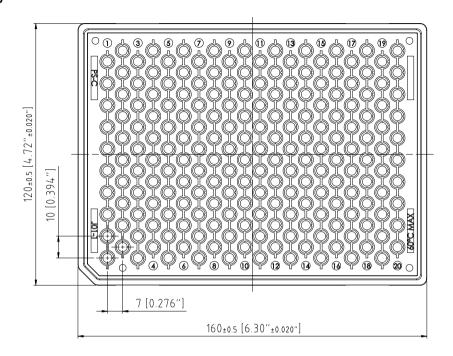
Pin 1: LD Cathode

Pin 2: LD Anode, PD Cathode (case)

Pin 3: PD Anode



Tray



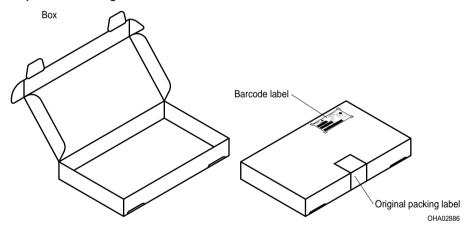
C63062-A4337-B1

Dimensions in mm [inches]

Barcode-Product-Label (BPL)



Transportation Packing and Materials



Dimensions of transportation box in mm

Width	Length	Height
170 ± 5	265 ± 5	45 ± 5

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Important notes of operation for laser diode

a) Electrical operation

OSRAMs laser diodes are designed for maximum performance and reliability. Operating the laser diode above the maximum rating even for very short periods of time can damage the laser diode or reduce its lifetime. The laser diode must be operated with a suitable power supply with minimized electrical noise.

The laser diode is very sensitive to electrostatic discharge (ESD). Proper precautions must be taken.

b) Mounting instructions

In order to maintain the lifetime of the laser diode proper heat management is essential. Due to the design of the laser diode heat is dissipated only through the base plate of the diode's body. A proper heat conducting interconnection between the diodes base plate and the heat sink must be maintained.



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